

# TIG065E8 — N-Channel IGBT

## Light-Controlling Flash Applications

### Features

- Low-saturation voltage
- Enhancement type
- Mounting Height 0.9mm, Mounting Area 8.12mm<sup>2</sup>
- Halogen free compliance
- Low voltage drive (2.5V)
- Built-in Gate-to-Emitter protection diode
- dv / dt guarantee\*

### Specifications

#### Absolute Maximum Ratings at Ta=25°C

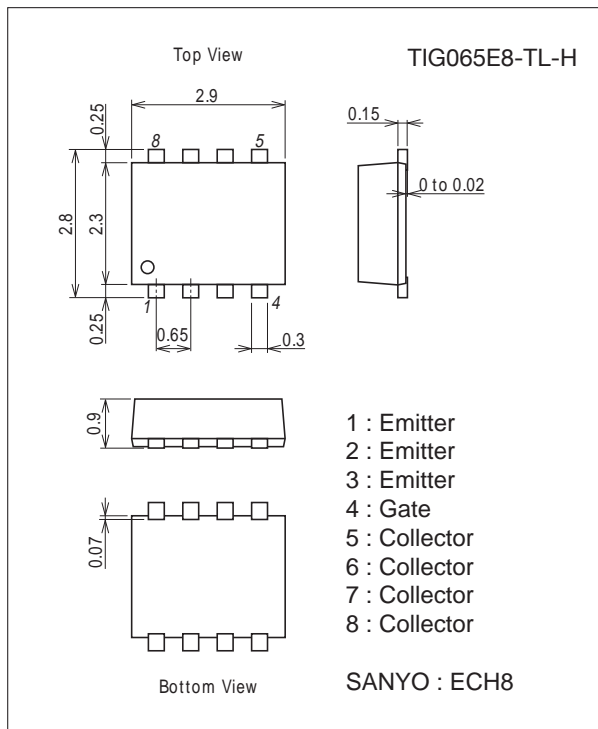
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Emitter Voltage	V <sub>CES</sub>		400	V
Gate-to-Emitter Voltage (DC)	V <sub>GES</sub>		±4	V
Gate-to-Emitter Voltage (Pulse)	V <sub>GES</sub>	PW≤1ms	±5	V
Collector Current (Pulse)	I <sub>CP</sub>	V <sub>GE</sub> =2.5V, C <sub>M</sub> =100μF	150	A
Maximum Collector-to-Emitter dv / dt	dv / dt	V <sub>CE</sub> ≤320V, starting T <sub>ch</sub> =25°C	400	V / μs
Channel Temperature	T <sub>ch</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-40 to +150	°C

\* : Concerning dv / dt (slope of Collector Voltage at the time of Turn-OFF), will be 100% screen-detected in the circuit shown as Fig. 1.

### Package Dimensions

unit : mm (typ)

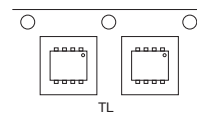
7011A-004



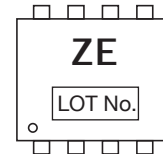
### Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3000 pcs./reel

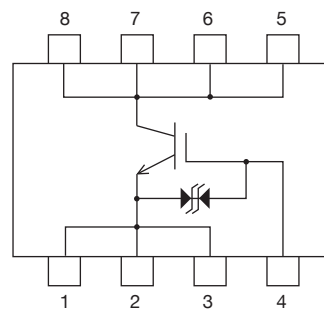
### Packing Type: TL



### Marking



### Electrical Connection

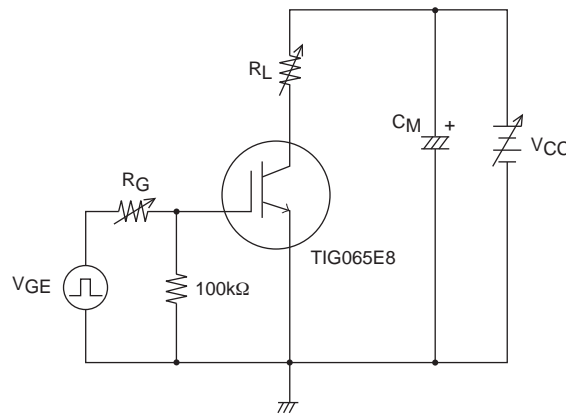


# TIG065E8

## Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
			min	typ	max		
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=2mA, V_{GE}=0V$	400			V	
Collector-to-Emitter Cutoff Current	$I_{CES}$	$V_{CE}=320V, V_{GE}=0V$			10	$\mu A$	
Gate-to-Emitter Leakage Current	$I_{GES}$	$V_{GE}=\pm 4V, V_{CE}=0V$			$\pm 10$	$\mu A$	
Gate-to-Emitter Threshold Voltage	$V_{GE(off)}$	$V_{CE}=10V, I_C=1mA$	0.4		0.9	V	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100A, V_{GE}=2.5V$		4.2	7	V	
Input Capacitance	$C_{ies}$	$V_{CE}=10V, f=1MHz$		3100		pF	
Output Capacitance	$C_{oes}$				30		pF
Reverse Transfer Capacitance	$C_{res}$				23		pF

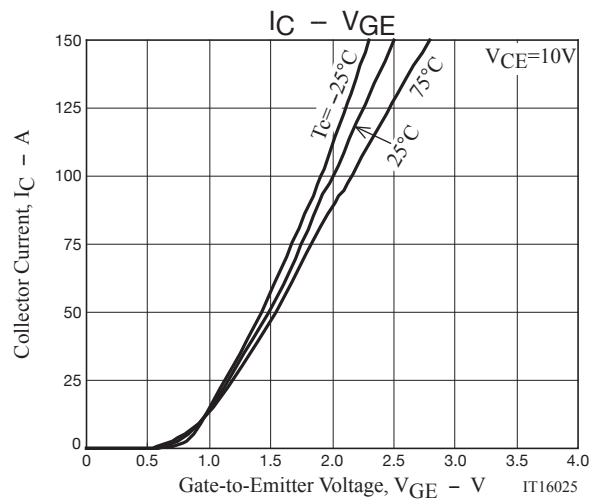
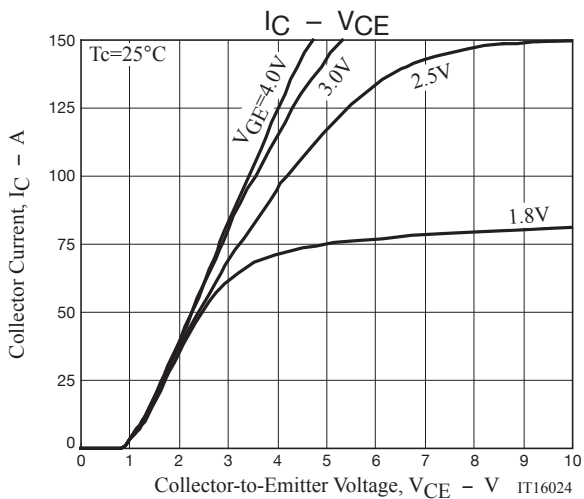
Fig.1 Large Current R Load Switching Circuit

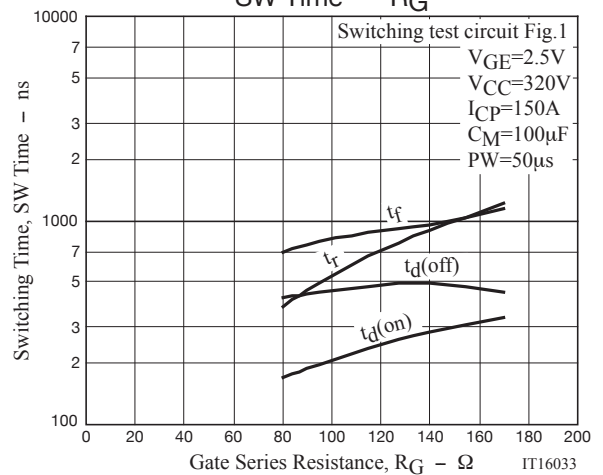
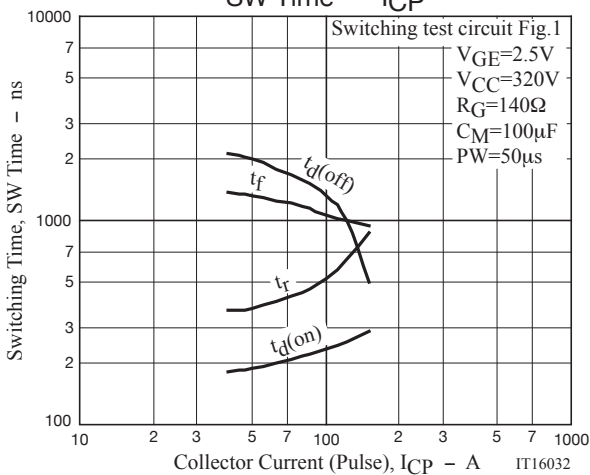
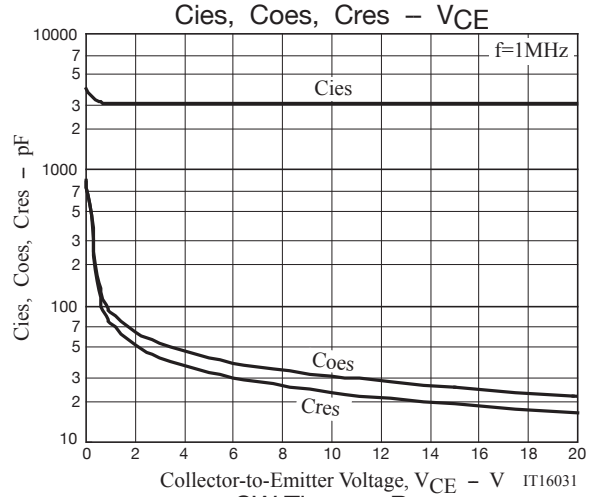
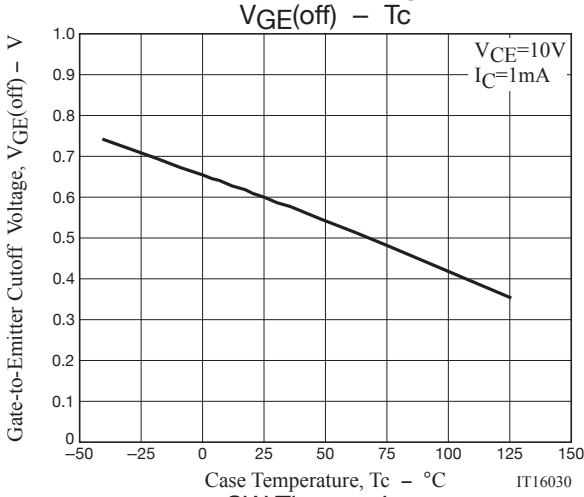
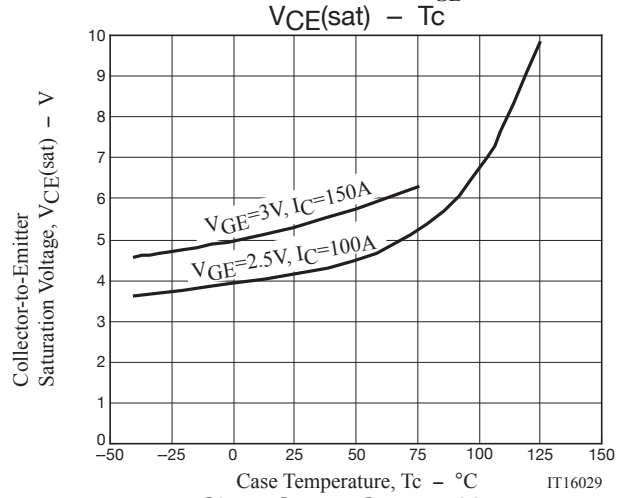
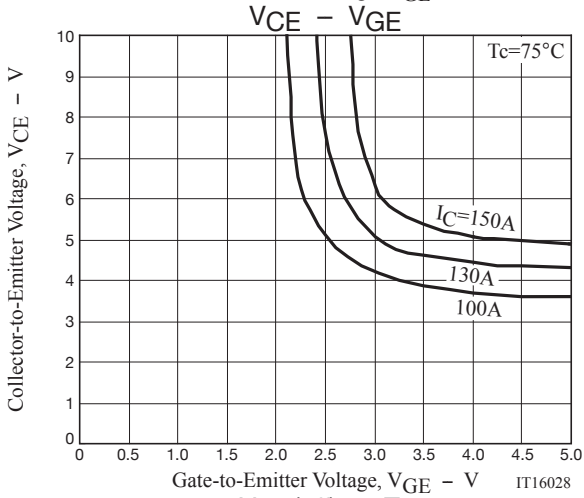
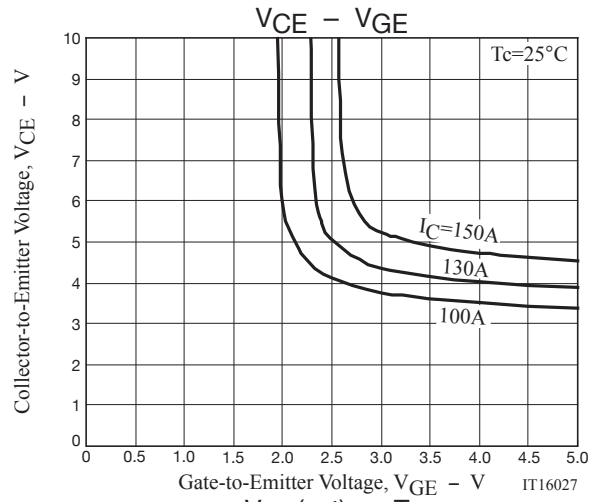
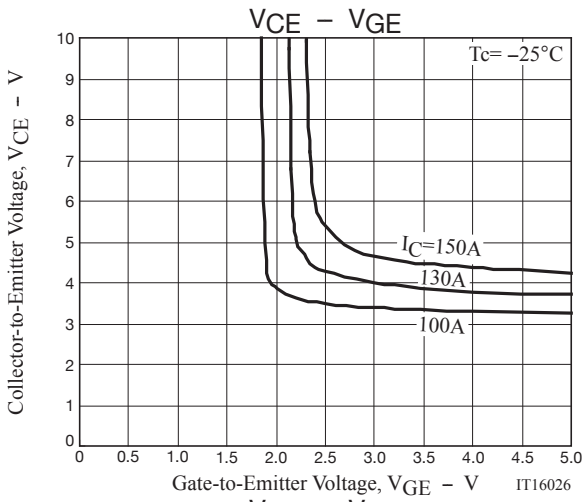


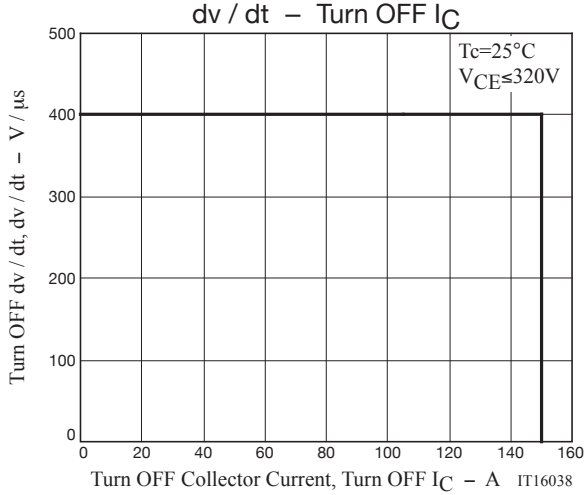
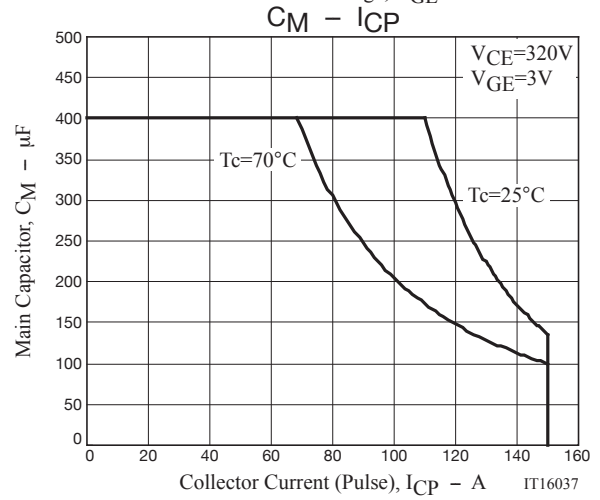
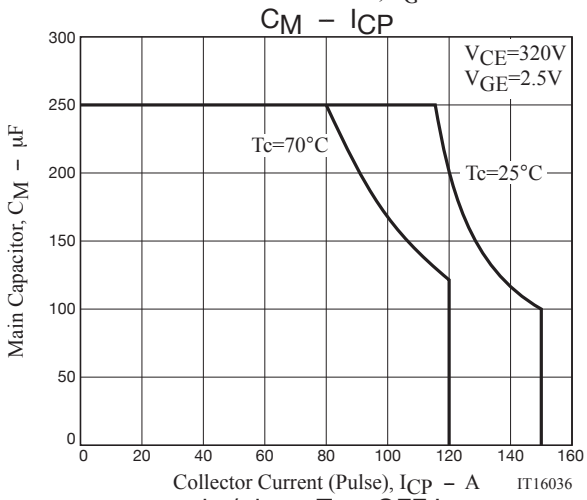
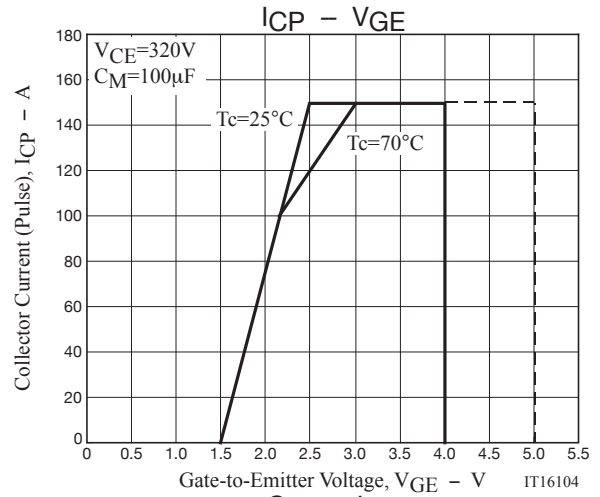
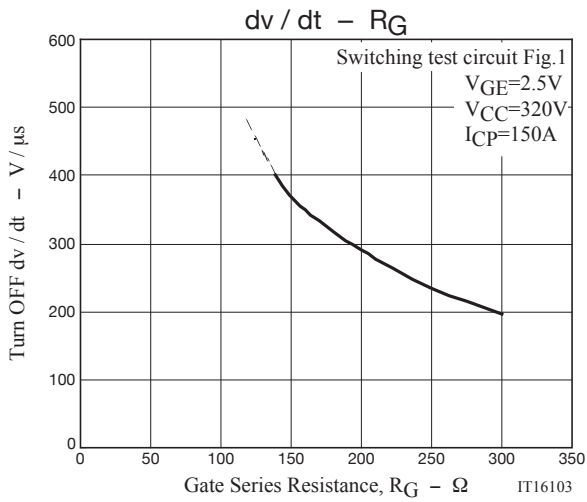
Note1. The collector voltage gradient  $dv / dt$  must be smaller than  $400V / \mu s$  to protect the device of gate-series resistance  $R_G$  when it is turned off.

## Ordering Information

Device	Package	Shipping	memo
TIG065E8-TL-H	ECH8	3,000pcs./reel	Pb Free and Halogen Free





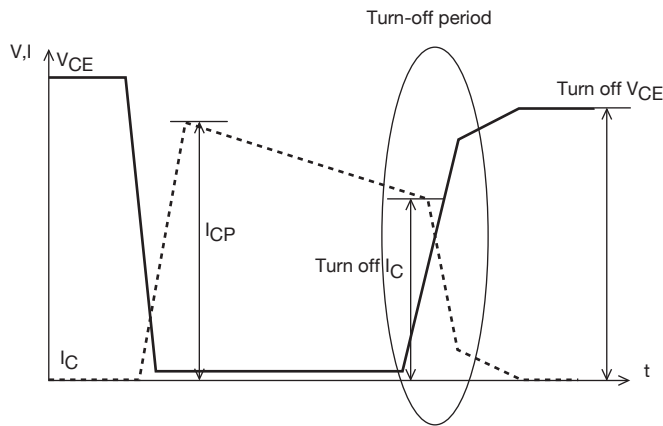


**Definition of dv/dt**

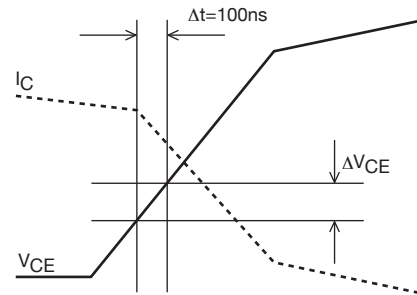
dv/dt is defined as the maximum slope of the below V<sub>CE</sub> curve during turn-off period.

$$dv/dt = \Delta V_{CE} / \Delta t = \Delta V_{CE} / 100ns$$

**Overall waveform**

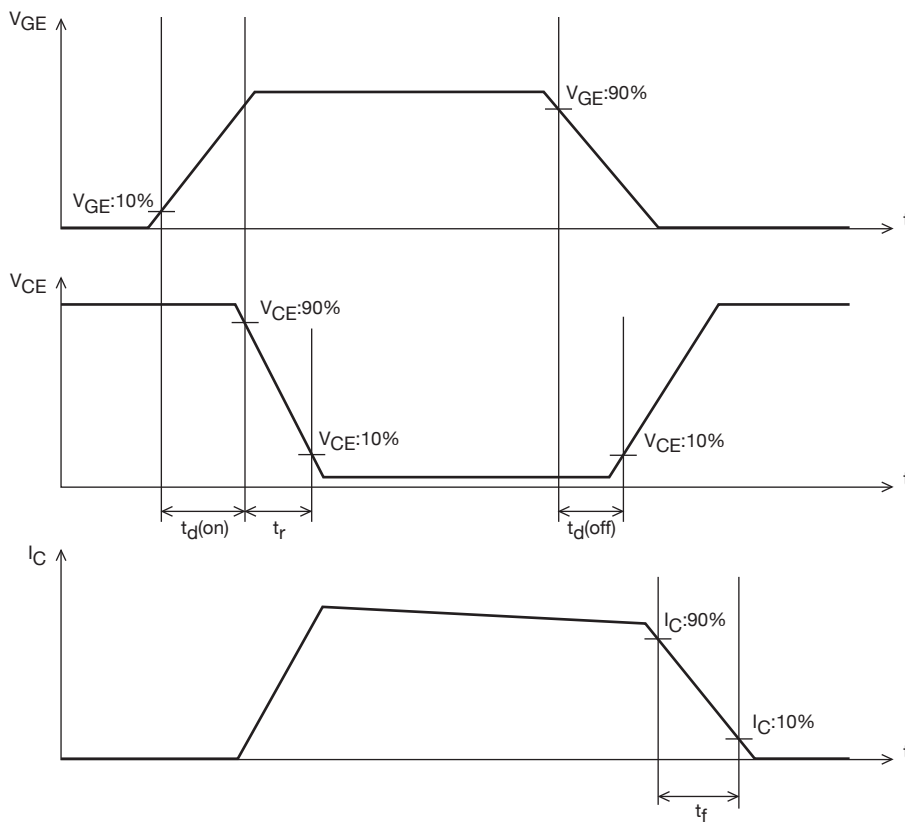


**Enlarged picture of turn-off period**



IT15323

**Definition of Switching Time**



IT15324

Embossed Taping Specification

TIG065E8-TL-H

1. Packing Format

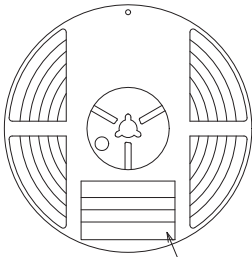
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit :mm)

Outer box label

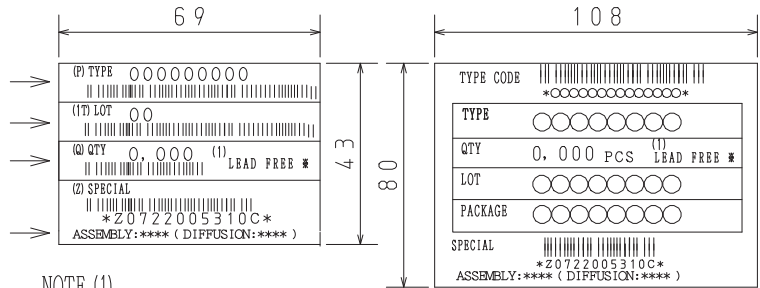
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.  
LOT No.  
Quantity  
Origin



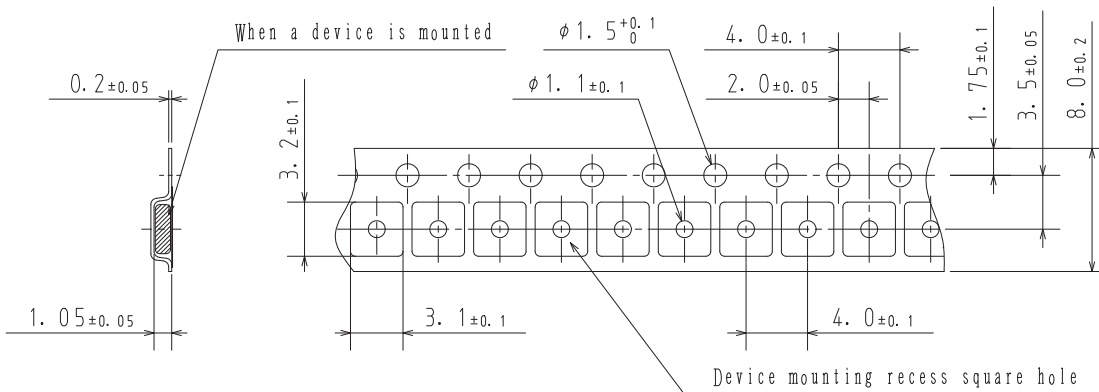
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

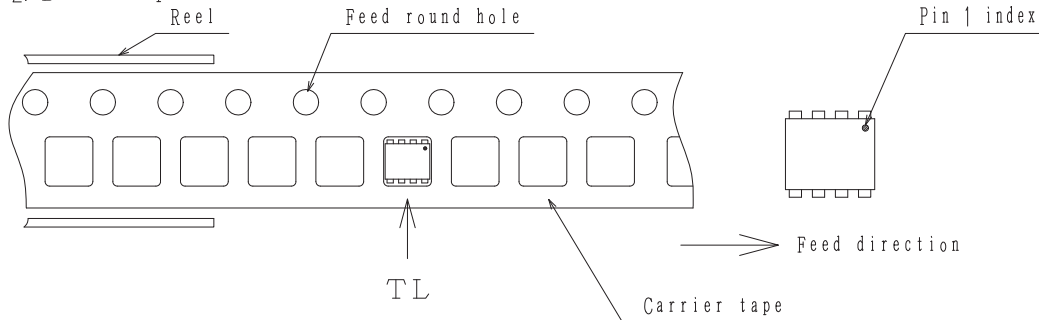
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

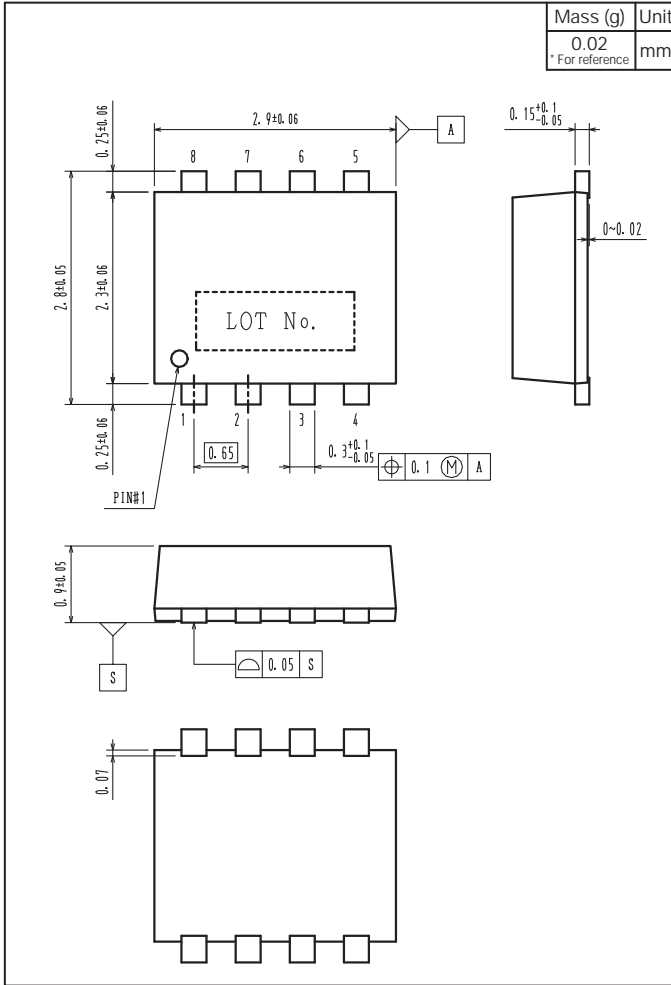


Those with pin 1 index on the feed hole side.....TL

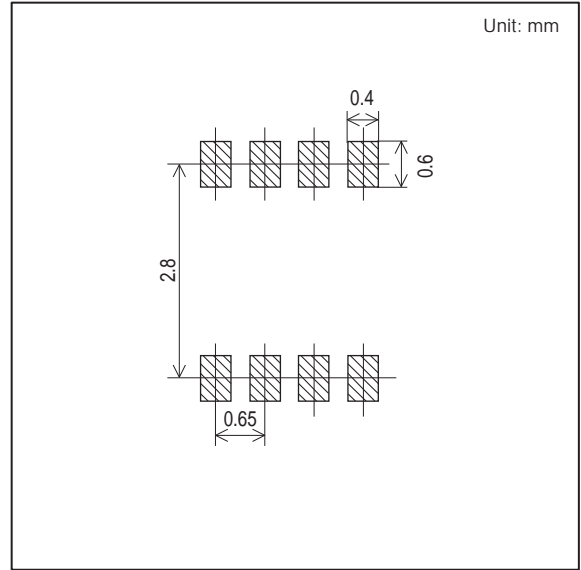
# TIG065E8

## Outline Drawing

TIG065E8-TL-H



## Land Pattern Example



Note : TIG065E8 has protection diode between gate and emitter but handling it requires sufficient care to be taken.

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